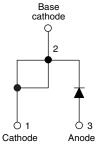


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Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A





TO-220 FULL-PAK

	2
O 1 Cathode	3 Anode

PRODUCT SUMMARY					
Package	TO-220FP				
I _{F(AV)}	10 A				
V _R	200 V, 400 V, 600 V				
V _F at I _F	1.2 V				
I _{FSM}	160 A				
t _{rr}	50 ns				
T _J max.	150 °C				
Diode variation	Single die				
Snap factor 0.5					

FEATURES

- 150 °C max. operation junction temperature
- Designed and qualified according JEDEC-JESD47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 approved
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912





HALOGEN FREE

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF0..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V _{RRM}		200 to 600	V			
I _{F(AV)}	Sinusoidal waveform	10	۸			
I _{FSM}		160	A			
t _{rr}	1 A, 100 A/μs	50	ns			
V _F	10 A, T _J = 25 °C	1.2	V			
T _J		- 40 to 150	°C			

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA			
VS-10ETF02FPPbF, VS-10ETF02FP-M3	200	300				
VS-10ETF04FPPbF, VS-10ETF04FP-M3	400	500	3			
VS-10ETF06FPPbF, VS-10ETF06FP-M3	600	700				

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T _C = 98 °C, 180° conduction half sine wave	10	
Maximum peak one cycle	I	10 ms sine pulse, rated V _{RRM} applied	150	Α
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	160	
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	112.5	A ² s
Maximum i-t for fusing		10 ms sine pulse, no voltage reapplied	160	A-5
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied	1600	A²√s



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	10 A, T _J = 25 °C		1.2	V
Forward slope resistance	r _t	T _J = 150 °C		23.5	mΩ
Threshold voltage	V _{F(TO)}	1J = 150 C		0.85	V
Maximum rayaraa laakaga aurrant	1	T _J = 25 °C	V Potad V	0.1	mA
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	V _R = Rated V _{RRM}	3.0	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	I _F at 10 Apk	200	ns	I _{FM} t
Reverse recovery current	I _{rr}	25 A/μs	2.75	Α	
Reverse recovery charge	Q_{rr}	25 °C	0.32	μC	dir/ Q _{rr}
Snap factor	S		0.6		I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	rage	T _J , T _{Stg}		- 40 to 150	°C
Maximum thermal resistar junction to case	ce	R_{thJC}	DC operation	2.5	
Maximum thermal resistar junction to ambient	ce	R _{thJA}		62	°C/W
Typical thermal resistance case to heatsink	,	R _{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque minimum maximum				6 (5)	kgf · cm
				12 (10)	(lbf · in)
Marking device			Case style TO-220 FULL-PAK	10ETF 10ETF 10ETF	04FP



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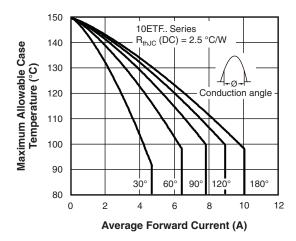


Fig. 1 - Current Rating Characteristics

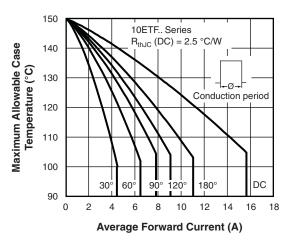


Fig. 2 - Current Rating Characteristics

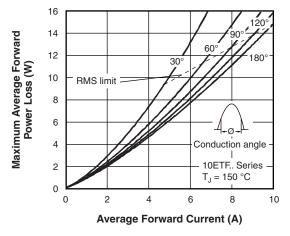


Fig. 3 - Forward Power Loss Characteristics

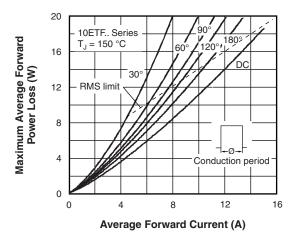


Fig. 4 - Forward Power Loss Characteristics

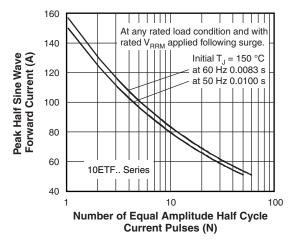


Fig. 5 - Maximum Non-Repetitive Surge Current

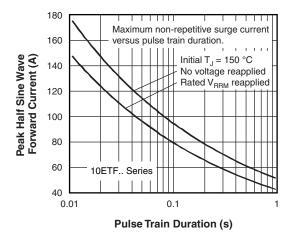


Fig. 6 - Maximum Non-Repetitive Surge Current

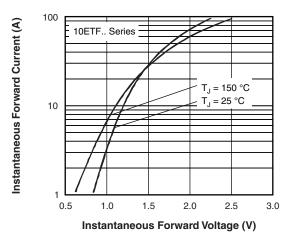


Fig. 7 - Forward Voltage Drop Characteristics

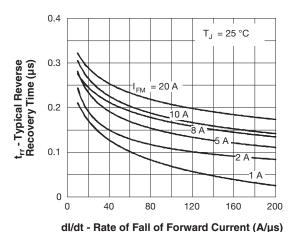


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

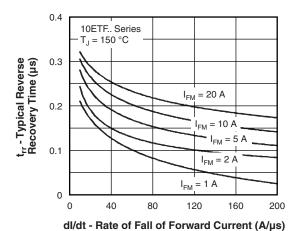


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

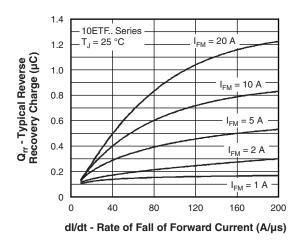


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

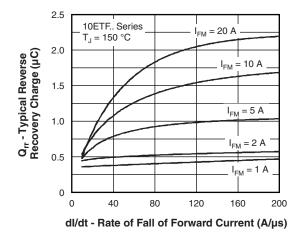
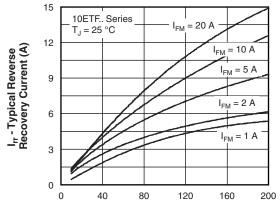


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C



dl/dt - Rate of Fall of Forward Current (A/ μ s)

Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

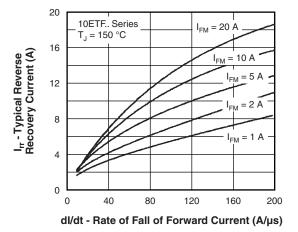


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

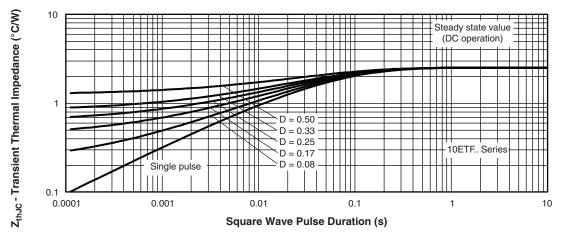
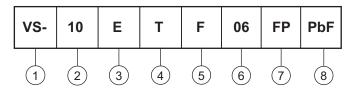


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (10 = 10 A)

3 - Circuit configuration:

E = Single diode

4 - Package:

T = TO-220

5 - Type of silicon:

F = Fast soft recovery rectifier

02 = 200 V 04 = 400 V

- Voltage code x 100 = V_{RRM}

Environmental digit:

06 = 600 V

7 - FULL-PAK

• PbF = Lead (Pb)-free and RoHS compliant

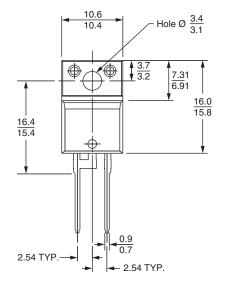
• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

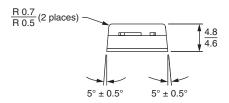
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETF02FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF02FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF04FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF04FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF06FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF06FP-M3	50	1000	Antistatic plastic tubes			

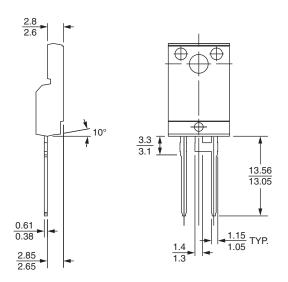
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95005</u>					
Dout moulting information	TO-220 FP PbF	www.vishay.com/doc?95009			
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440			

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DIMENSIONS in millimeters







Lead assignments

<u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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